## PATENT MTC04 P-106

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Examiner

George A. Goudreau

Group

1763

Confirmation No.

4253

Applicant

Imad Mahawili, PhD

Serial No.

09/488,309

Filed

January 20, 2000

For

REACTOR WITH REMOTE PLASMA SYSTEM AND

METHOD OF PROCESSING A SEMICONDUCTOR

**SUBSTRATE** 

Commissioner for Patents Washington, D.C. 20231

Dear Sir:

## RESPONSE

In response to the Office Action mailed June 19, 2002, having a three-month period of response ending September 19, 2002, Applicant wishes to amend his application as follows:

## IN THE CLAIMS:

Please cancel Claims 1, 4, 7, 10, 16, 32, 57, 59-61, and 64-77. Please amend Claims 2, 5, 6, 8, 9, 11, 15, 17, 20, 22, 24, 33, 34, 35, 37-55, 58, 62, and 63 as follows:

- 2. The reactor according to Claim 22, further comprising a heater for selectively heating the substrate in said processing chamber.
  - 5. The reactor according to Claim 22, wherein said plasma generator generates an electromagnetic field, said electromagnetic field for ionizing the gas into a gas plasma.
    - 6. The reactor according to Claim 22, wherein said plasma generator ionizes said gas exteriorly of said processing chamber to isolate the substrate from said electromagnetic field.